

DESCRIPTION

The RCLAMP0502B is an ultra-low capacitance Transient Voltage Suppressor (TVS) designed to provide electrostatic discharge (ESD) protection for high-speed data interfaces. With typical capacitance of 0.2pF (I/O to I/O) only, RCLAMP0502B is designed to protect parasitic-sensitive systems against over-voltage and over-current transient events. It complies with IEC 61000-4-2 (ESD), Level 4 (±15kV air, ±8kV contact discharge), IEC 61000-4-4 (electrical fast transient - EFT) (40A, 5/50 ns), very fast charged device model (CDM) ESD and cable discharge event (CDE), etc.

RCLAMP0502B uses small SOT-523 package.Each RCLAMP0502B device can protect two high-speed data lines. The combined features of low capacitance, small size and high ESD robustness make RCLAMP0502B ideal for high-speed data port and high-frequency line applications. The low clamping voltage of the RCLAMP0502B guarantees a minimum stress on the protected IC.

FEATURES

♦ Transient protection for high-speed data lines IEC 61000-4-2 (ESD) ±15kV (Air) ±8kV (Contact)

IEC 61000-4-4 (EFT) 40A (5/50 ns) Cable Discharge Event (CDE)

- ♦Small package (1.6mm×0.8mm×0.75mm)
- ♦Protects two data lines
- ♦Low capacitance: 0.2pF Typical (I/O-I/O)
- ♦Low leakage current
- ♦Low clamping voltage

MACHANICAL DATA

- ♦SOT-523 package
- ♦Flammability Rating: UL 94V-0
- ♦ Packaging: Tape and Reel
- ♦ High temperature soldering guaranted: 260/10s
- ♦Reel size: 7 inch
- ♦MSL1

ORDERING INFORMATION

♦ Package: SOT-523

♦ Marking: 52L

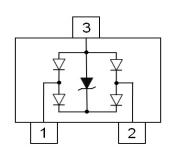
→ Material: Halogen free→ Packing: Tape & Reel

♦ Quantity per reel: 3,000pcs

APPLICATIONS

- ♦ Serial ATA
- ♦ Desktops, Servers and Notebooks
- ♦PCI Express
- ♦MDDI Ports
- ♦USB Data Line Protection
- **♦HDMI Ports**
- ♦ Digital Visual Interfaces (DVI)

PIN CONFIGURATION



PACKAGE OUTLINE



ABSOLUTE MAXIMUM RATING							
Symbol	Parameter	Value	Units				
P _{PP}	Peak Pulse Power (8/20µs)	60	W				
V _{ESD}	ESD per IEC 61000-4-2 (Air) ESD per IEC 61000-4-2 (Contact)	±20 ±20	kV				
T _{OPT}	Operating Temperature	-55/+125	°C				
T _{STG}	Storage Temperature	-55/+125	°C				

ELECTRICAL CHARACTERISTICS (Tamb=25°C)									
Symbol	Parameter	Test Condition	Min	Тур	Max	Units			
V_{RWM}	Reverse Working Voltage	I/O to GND			5.0	V			
V_{BR}	Reverse Breakdown Voltage	I _⊤ = 1mA Between I/O and GND	6.0			V			
I _R	Reverse Leakage Current	V _{RWM} = 5V Between I/O and GND			100	nA			
V _F	Forward Voltage	I _T = 10mA Between I/O and GND			1.2	V			
Vc	Clamping Voltage	I _{PP} = 1A, t _p = 8/20μs Between I/O and GND			10	V			
		I _{PP} = 4A, t _p = 8/20μs Between I/O and GND			15	V			
Ст	Total Capacitance	V _R = 0V, f = 1MHz Between I/O and GND		0.4	0.6	pF			
		V _R = 0V, f = 1MHz Between I/O and I/O		0.2	0.3	pF			



ELECTRICAL CHARACTERISTICS CURVE Fig 1 Power Derating Curve dd % of Rated Power or Ambient Temperature (℃)

